

CMLSH05-4DO

SURFACE MOUNT
DUAL ISOLATED, LOW V_F
OPPOSING SILICON
SCHOTTKY DIODES

PICOmini™



SOT-563 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMLSH05-4DO consists of two (2) individual electrically isolated 40 volt Schottky Diodes with opposing polarity and packaged in a space saving SOT-563 surface mount case. This PICOmini™ device has been designed for applications requiring a low forward voltage drop.

MARKING CODE: CO4

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Peak Repetitive Reverse Voltage
Continuous Forward Current
Peak Repetitive Forward Current, $t_p \leq 1.0\text{ms}$
Peak Forward Surge Current, $t_p = 8.0\text{ms}$
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL

V_{RRM} 40
 I_F 500
 I_{FRM} 3.5
 I_{FSM} 10
 P_D 250
 T_J, T_{stg} -65 to +150
 Θ_{JA} 500

UNITS

V
mA
A
A
mW
 $^\circ\text{C}$
 $^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS PER DIODE: ($T_A=25^\circ\text{C}$ unless otherwise noted)

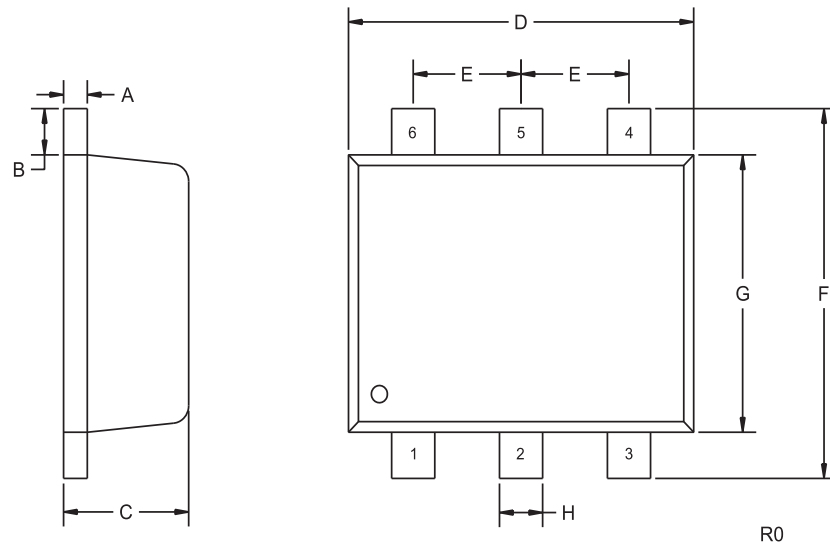
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_R	$V_R=10\text{V}$		20	μA
I_R	$V_R=30\text{V}$		100	μA
BV_R	$I_R=500\mu\text{A}$	40		V
V_F	$I_F=100\mu\text{A}$		0.13	V
V_F	$I_F=1.0\text{mA}$		0.21	V
V_F	$I_F=10\text{mA}$		0.27	V
V_F	$I_F=100\text{mA}$		0.35	V
V_F	$I_F=500\text{mA}$		0.47	V
C_T	$V_R=1.0\text{V}, f=1.0\text{MHz}$		50	pF

R2 (20-January 2010)

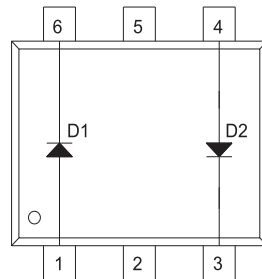
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SOT-563 CASE - MECHANICAL OUTLINE



PIN CONFIGURATION



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.004	0.007	0.10	0.18
B	0.008		0.20	
C	0.022	0.024	0.56	0.60
D	0.059	0.067	1.50	1.70
E	0.020		0.50	
F	0.061	0.067	1.55	1.70
G	0.047		1.20	
H	0.006	0.012	0.15	0.30

SOT-563 (REV: R0)

LEAD CODE:

- 1) Anode D1
- 2) NC
- 3) Cathode D2
- 4) Anode D2
- 5) NC
- 6) Cathode D1

MARKING CODE: CO4

R2 (20-January 2010)